

Features

- $BV_{CE0} > 80V$
- Small Form Factor Thermally Efficient Package. Enables Higher Density End Products
- $I_C = 1A$ Continuous Collector Current
- $I_{CM} = 2A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < 500mV @ 0.5A$
- Complementary PNP Types: DXTP06080BFG
- Wettable Flank For Improved Optical Inspection
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

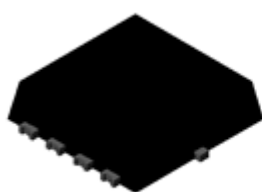
Mechanical Data

- Case: PowerDI®3333-8
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.03 grams (Approximate)

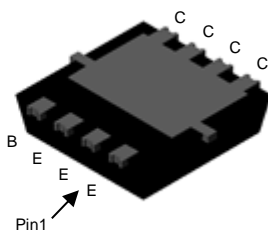
Applications

- Medium Power Switching
- Power Amplification
- AF Driver and Output Stages

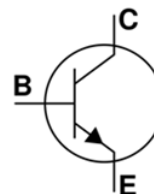
PowerDI3333-8 (SWP) (Type UX)



Top View



Bottom View



Device Symbol

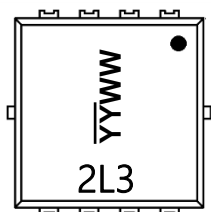
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DXTN06080BFG-7	Standard	2L3	7	12	2,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2L3= Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 21 = 2021)
 WW = Week Code (01 to 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	100	V
Collector-Emitter Voltage	V _{CEO}	80	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	1	A
Peak Pulse Collector Current	I _{CM}	2	A
Continuous Base Current	I _B	100	mA
Peak Pulse Base Current	I _{BM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

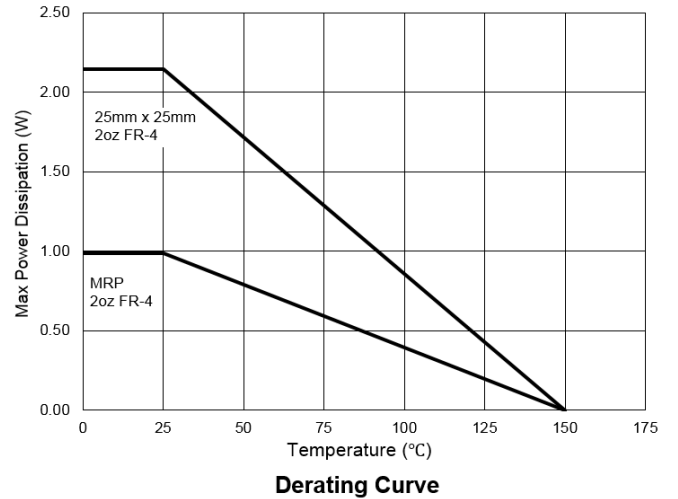
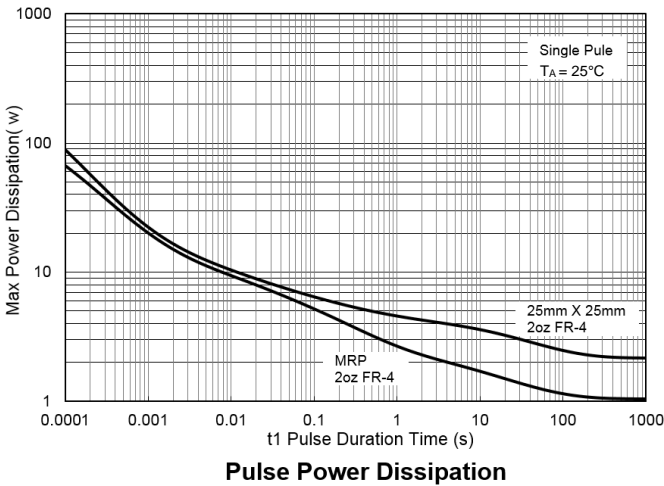
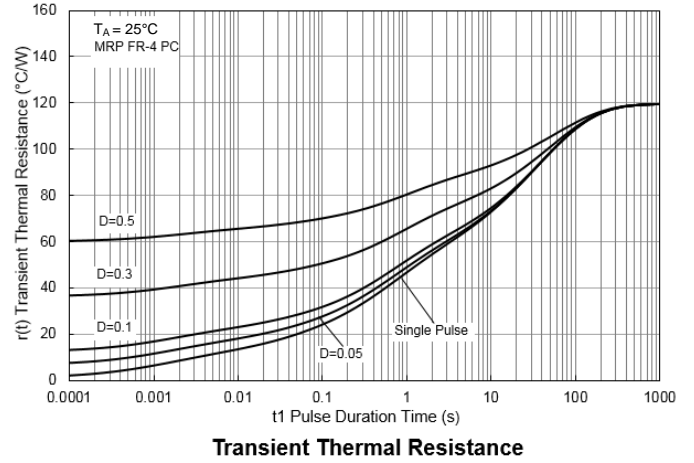
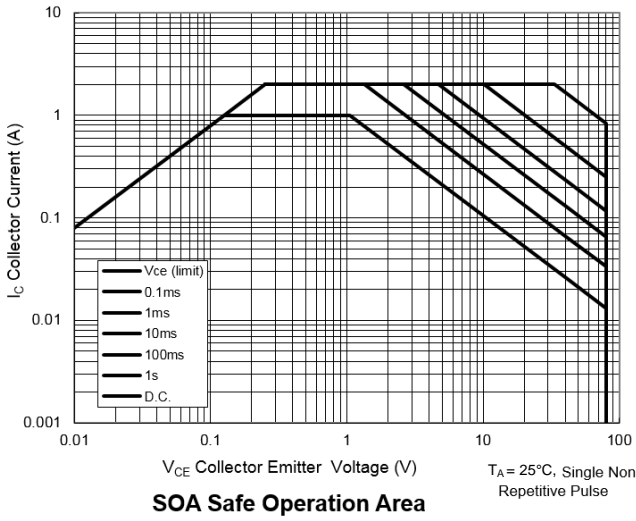
Characteristic	Symbol	Value	Unit	
Power Dissipation	P _D	(Note 5)	1	W
		(Note 6)	2.1	W
Thermal Resistance, Junction to Ambient	R _{θJA}	(Note 5)	128	°C/W
		(Note 6)	59	°C/W
Thermal Resistance, Junction to Leads (Note 7)	R _{θJL}	10.7	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
 - 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
 - 7. Thermal resistance from junction to solder-point (at the collector tab).
 - 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

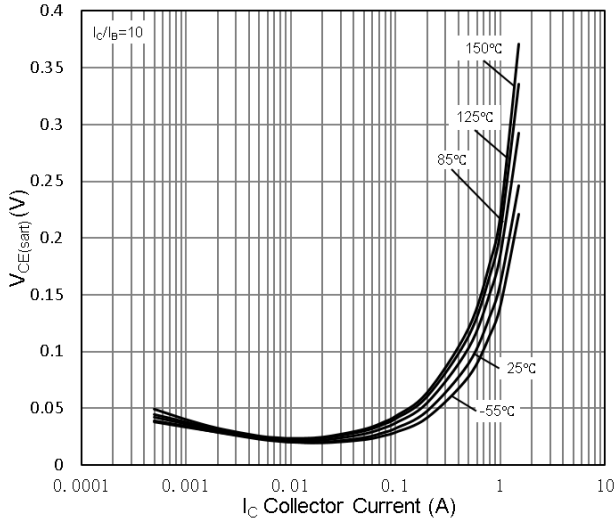


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

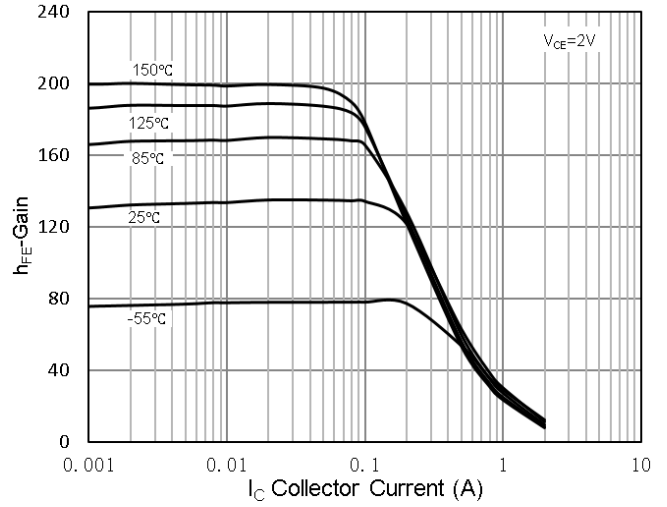
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	300	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	80	139	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.3	—	V	I _E = 100μA
Collector-Base Cut-Off Current	I _{CBO}	—	8 0.1	50 20	nA μA	V _{CB} = 100V V _{CB} = 80V, T _A = +150°C
Collector-Emitter Cut-Off Current	I _{CES}	—	6	20	nA	V _{CE} = 80V
Emitter Cut-Off Current	I _{EBO}	—	0.1	20	nA	V _{EB} = 6V
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	25	129	—	—	I _C = 5mA, V _{CE} = 2V
		100	127	250		I _C = 150mA, V _{CE} = 2V
		40	60	—		I _C = 500mA, V _{CE} = 2V
		25	36	—		I _C = 800mA, V _{CE} = 2V
		—	28	—		I _C = 1A, V _{CE} = 2V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	—	91 135	250 500	mV	I _C = 500mA, I _B = 50mA I _C = 800mA, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	—	0.821	1	V	I _C = 500mA, V _{CE} = 2V
Input Capacitance	C _{ibo}	—	160	—	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	C _{obo}	—	11	—	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	f _T	—	130	—	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Switching Characteristics	t _{delay}	—	8.6	—	ns	V _{CC} = -10V, I _C = 500mA I _{B1} = -I _{B2} = 50mA
	t _{rise}	—	3.8	—	ns	
	t _{storage}	—	491	—	ns	
	t _{fall}	—	171	—	ns	

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

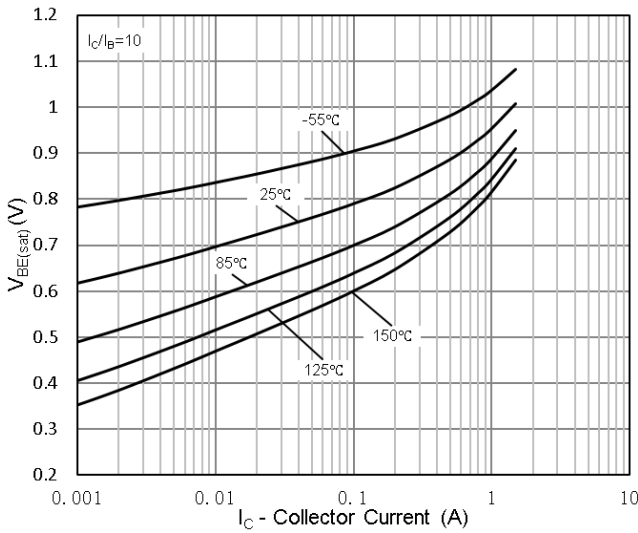
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



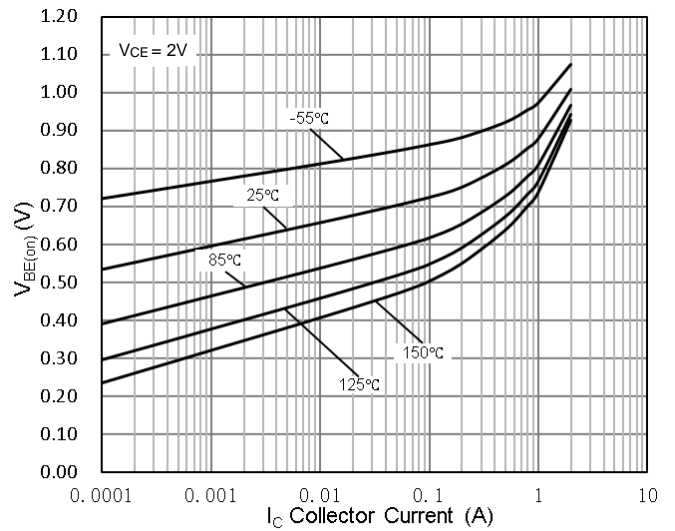
V_{CE(sat)} vs I_C



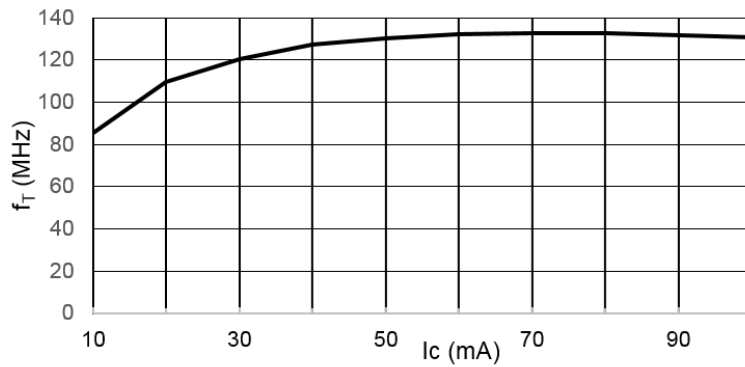
h_{FE} vs I_C



V_{BE(sat)} vs I_C



V_{BE(on)} vs I_C

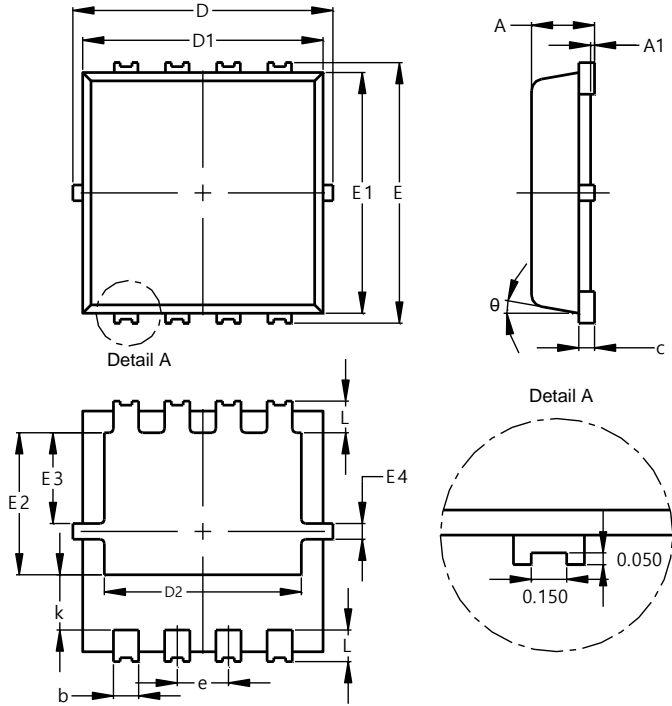


f_T vs I_C

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI3333-8 (SWP) (Type UX)

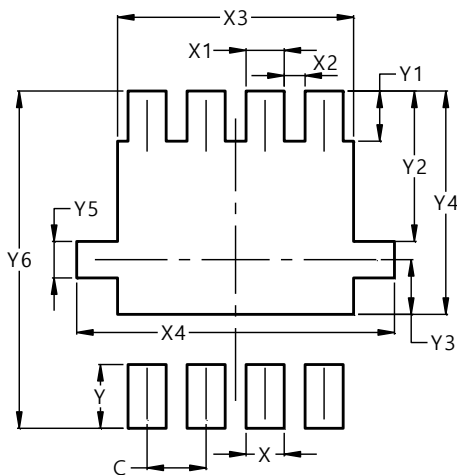


PowerDI3333-8 (SWP) (Type UX)			
Dim	Min	Max	Typ
A	0.75	0.85	0.80
A1	0.00	0.05	--
b	0.25	0.40	0.32
c	0.10	0.25	0.15
D	3.20	3.40	3.30
D1	2.95	3.15	3.05
D2	2.30	2.70	2.50
E	3.20	3.40	3.30
E1	2.95	3.15	3.05
E2	1.60	2.00	1.80
E3	0.95	1.35	1.15
E4	0.10	0.30	0.20
e	--	--	0.65
k	0.50	0.90	0.70
L	0.30	0.50	0.40
θ	0°	12°	10°
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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